

## **SLG7RN46720**

**GreenPAK** ™

## SA\_ADCPAK\_SLG583V

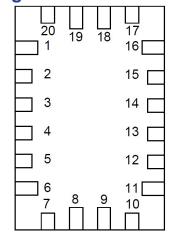
### **General Description**

Renesas SLG7RN46720 is a low power and small form device. The SoC is housed in a 2mm x 3mm STQFN package which is optimal for using with small devices.

#### **Features**

- Low Power Consumption
- Pb Free / RoHS Compliant
- Halogen Free
- STQFN 20 Package

## **Pin Configuration**



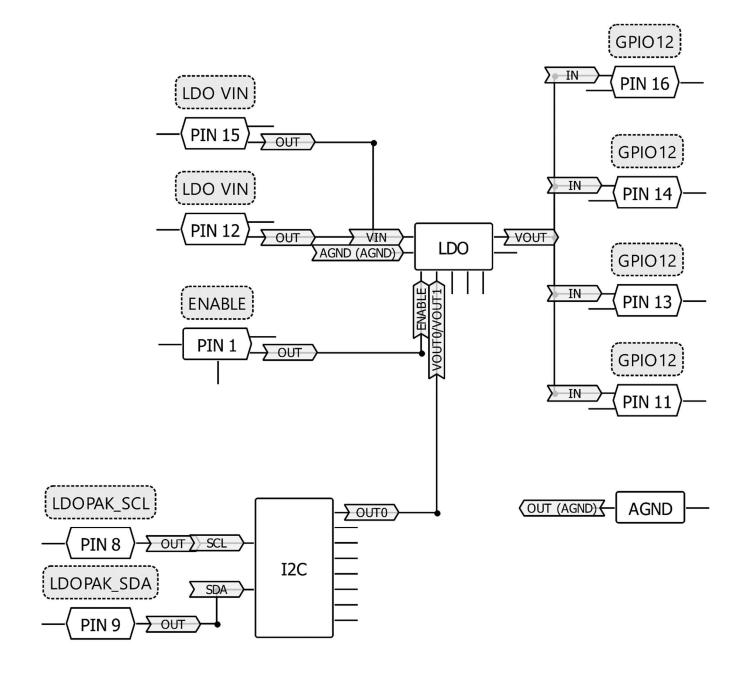
STQFN-20 (Top view)

### Pin name

Pin#	Pin name	Pin#	Pin name
1	ENABLE	11	AGND
2	NC	12	AGND
3	NC	13	AGND
4	NC	14	AGND
5	NC	15	AGND
6	NC	16	AGND
7	VDD	17	AGND
8	LDOPAK_SCL	18	NC
9	LDOPAK_SDA	19	NC
10	NC	20	GND



## **Block Diagram**





**Pin Configuration** 

Pin #	Pin Name	Туре	Pin Description	Internal Resistor
1	ENABLE	Digital Input	Digital Input without Schmitt trigger	floating
2	NC		Keep Floating or Connect to GND	
3	NC		Keep Floating or Connect to GND	
4	NC		Keep Floating or Connect to GND	
5	NC		Keep Floating or Connect to GND	
6	NC		Keep Floating or Connect to GND	
7	VDD	PWR	Supply Voltage	
8	LDOPAK_SCL	Digital Input	Digital Input without Schmitt trigger	floating
9	LDOPAK_SDA	Digital Input	Digital Input without Schmitt trigger	floating
10	NC		Keep Floating or Connect to GND	
11	AGND	Analog Output	LDO VOUT Analog Output	floating
12	AGND	Analog Input	LDO VIN Analog Input	floating
13	AGND	Analog Output	LDO VOUT Analog Output	floating
14	AGND	Analog Output	LDO VOUT Analog Output	floating
15	AGND	Analog Input	LDO VIN Analog Input	floating
16	AGND	Analog Output	LDO VOUT Analog Output	floating
17	AGND	AGND	Ground	
18	NC		Keep Floating or Connect to GND	
19	NC		Keep Floating or Connect to GND	
20	GND	GND	Ground	

**Ordering Information** 

Part Number	Package Type
SLG7RN46720V	20-pin STQFN - Tape and Reel (3k units)



### **Absolute Maximum Conditions**

Parameter	Min.	Max.	Unit
Supply Voltage on VDD relative to GND	-0.3	7	V
DC Input Voltage	GND - 0.5V	VDD + 0.5V	V
Current at Input Pin	-1.0	1.0	mA
Input leakage (Absolute Value)		1000	nA
Storage Temperature Range	-65	150	Ĵ
Junction Temperature		150	Ĵ
ESD Protection (Human Body Model)	2000		V
ESD Protection (Charged Device Model)	1300		V
Moisture Sensitivity Level	1		

#### **Electrical Characteristics**

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
$V_{DD}$	Supply Voltage		2.3	3.3	5.5	V
TA	Operating Temperature		-40	25	85	°C
C <sub>VDD</sub>	Capacitor Value at VDD			0.1		μF
CIN	Input Capacitance			4	-	pF
lα	Quiescent Current	VDD=5.5V; PIN8 and PIN9 HIGH, PIN1 LOW; floating outputs		1		μΑ
Vo	Maximal Voltage Applied to any PIN in High-Impedance State				VDD+0.3	<b>\</b>
	Maximum Average or DC	T <sub>J</sub> = 85°C			73	mA
I <sub>VDD</sub>	Current Through VDD Pin (Per chip side, see Note 2)	T <sub>J</sub> = 110°C			35	mA
	Maximum Average or DC	T <sub>J</sub> = 85°C			152	mA
I <sub>GND</sub>	Current Through GND Pin (Per chip side, see Note 2)	T <sub>J</sub> = 110°C			72	mA
ViH	HIGH-Level Input Voltage	Logic Input	0.7xVDD		VDD+0.3	V
VIL	LOW-Level Input Voltage	Logic Input	GND-0.3	-	0.3xVDD	V
T <sub>SU</sub>	Startup Time	From VDD rising past PON <sub>THR</sub>		1.3		ms
PONTHR	Power On Threshold	V <sub>DD</sub> Level Required to Start Up the Chip	1.34	1.55	1.74	V
POFFTHR	Power Off Threshold	V <sub>DD</sub> Level Required to Switch Off the Chip	1.05	1.25	1.45	V

#### Note:

- 1. DC or average current through any pin should not exceed value given in Absolute Maximum Conditions.
- 2. The GreenPAK's power rails are divided in two sides. PINs 1, 2, 3, 4, 5 and 6 are connected to one side, PINs 8, 9, 10, 18 and 19 to another.
- 3. Guaranteed by Design.

## I<sup>2</sup>C Specifications

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
FscL	Clock Frequency, SCL	$V_{DD} = (2.35.5) V$			400	kHz
tLOW	Clock Pulse Width Low	$V_{DD} = (2.35.5) V$	1300			ns
thigh	Clock Pulse Width High	$V_{DD} = (2.35.5) V$	600			ns
tı		$V_{DD} = 2.5V \pm 8\%$			168	ns





	Input Filter Spike	$V_{DD} = 3.3V \pm 10\%$		 157	ns
	Suppression (SCL, SDA)	$V_{DD} = 5.0V \pm 10\%$		 156	ns
taa	Clock Low to Data Out Valid	$V_{DD} = (2.35.5) V$		 900	ns
t <sub>BUF</sub>	Bus Free Time between Stop and Start	V <sub>DD</sub> = (2.35.5) V	1300	 	ns
t <sub>HD_STA</sub>	Start Hold Time	V <sub>DD</sub> = (2.35.5) V	600	 	ns
t <sub>SU_STA</sub>	Start Set-up Time	$V_{DD} = (2.35.5) V$	600	 	ns
t <sub>HD_DAT</sub>	Data Hold Time	$V_{DD} = (2.35.5) V$	0	 	ns
t <sub>SU_DAT</sub>	Data Set-up Time	$V_{DD} = (2.35.5) V$	100	 	ns
t <sub>R</sub>	Inputs Rise Time	$V_{DD} = (2.35.5) V$		 300	ns
t <sub>F</sub>	Inputs Fall Time	$V_{DD} = (2.35.5) V$		 300	ns
t <sub>SU_STO</sub>	Stop Set-up Time	V <sub>DD</sub> = (2.35.5) V	600	 	ns
t <sub>DH</sub>	Data Out Hold Time	V <sub>DD</sub> = (2.35.5) V	50	 	ns

**Chip address** 

HEX	BIN	DEC
0x70	1110000	112



### **I2C Description**

#### 1. I2C Basic Command Structure

Each command to the I2C Serial Communications block begins with a Control Byte. The bits inside this Control Byte are shown in Figure 1. After the Start bit, the first four bits are a control code, which can be set by the user in reg<1867:1864>. The Block Address is the next three bits (A10, A9, A8), which will define the most significant bits in the addressing of the data to be read ("1") or written ("0") by the command. This Control Byte will be followed by an Acknowledge bit (ACK).

With the exception of the Current Address Read command, all commands will have the Control Byte followed by the Word Address. The Word Address, in conjunction with the three address bits in the Control Byte, will define the specific data byte to be read or written in the command. Figure 1 shows this basic command structure.

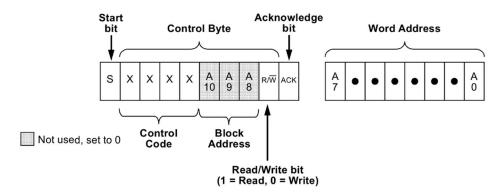


Figure 1. I2C Basic Command Structure

#### 2. I2C Serial General Timing

Shown in Figure 2 is the general timing characteristics for the I2C Serial Communications block.

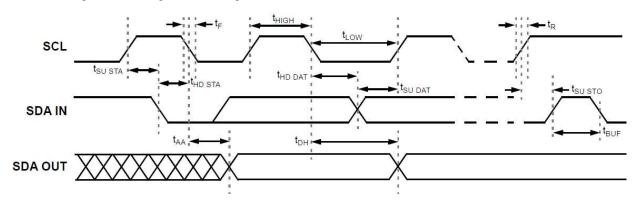


Figure 2. I2C Serial General Timing



#### 3. I2C Serial Communications: Read and Write Commands

Following the Start condition from the master, the Control Code [4 bits], the block address [3 bits] and the R/W bit (set to "0"), is placed onto the bus by the Bus Master. After the I2C Serial Communications block has provided an Acknowledge bit (ACK) the next byte transmitted by the master is the Word Address. The Block Address is the next three bits, and is the higher order addressing bits (A10, A9, A8), which when added to the Word Address will together set the internal address pointer in the SLG7RN46720V to the correct data byte to be written. After the SLG7RN46720Vsends another Acknowledge bit, the Bus Master will transmit the data byte to be written into the addressed memory location. The SLG7RN46720V again provides an Acknowledge bit and then the Bus Master generates a Stop condition. The internal write cycle for the data will take place at the time that the SLG7RN46720V generates the Acknowledge bit.

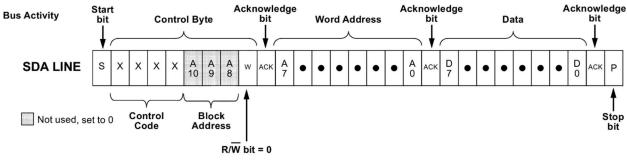
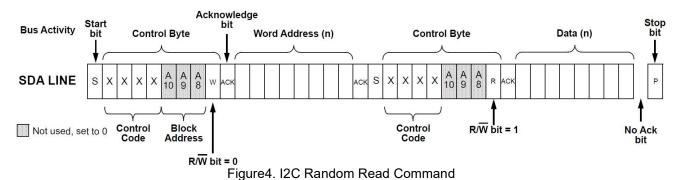


Figure 3. I2C Write Command

The Random Read command starts with a Control Byte (with  $R/\overline{W}$  bit set to "0", indicating a write command) and Word Address to set the internal byte address, followed by a Start bit, and then the Control Byte for the read (exactly the same as the Byte Write command). The Start bit in the middle of the command will halt the decoding of a Write command, but will set the internal address counter in preparation for the second half of the command. After the Start bit, the Bus Master issues a second control byte with the  $R/\overline{W}$  bit set to "1", after which the SLG7RN46720V issues an Acknowledge bit, followed by the requested eight data bits.



4. I2C register control data

in index register contact data						
Address Byte	Register Bit	Block	Function			
0xF4	reg<1952>	Virtual Input <0>	Adjust I2C OUT0 to LOW/HIGH to control LDO			



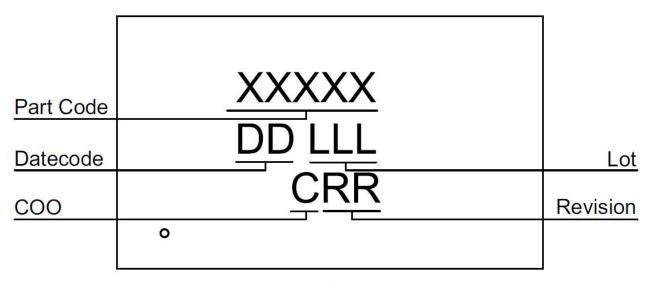


#### 5. I2C Commands:

1. [start] [0x08] [w] [0xF4] [xxxxxxx(OUT0)] [stop] // Adjust I2C OUT0 to LOW/HIGH



## **Package Top Marking**



XXXXX - Part ID Field: identifies the specific device configuration

DD - Date Code Field: Coded date of manufacture

LLL - Lot Code: Designates Lot #

C - Assembly Site/COO: Specifies Assembly Site/Country of Origin

RR - Revision Code: Device Revision

Datasheet Revision	Programming Code Number	Lock Status	Checksum	Part Code	Revision	Date
0.10	001	U	0xEFF9D8E3			07/13/2023

Lock coverage for this part is indicated by  $\sqrt{\ }$ , from one of the following options:

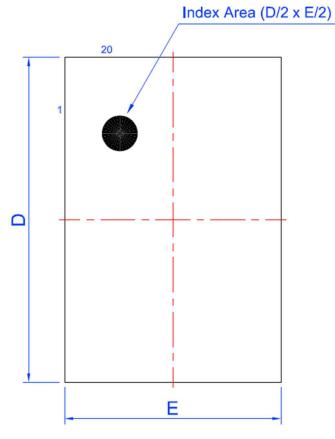
 Unlocked
Locked for read, bits <1535:0>
Locked for write, bits <1535:0>
Locked for write all bits
Locked for read and write bits <1535:0>
Locked for read bits <1535:0> and write of all bits

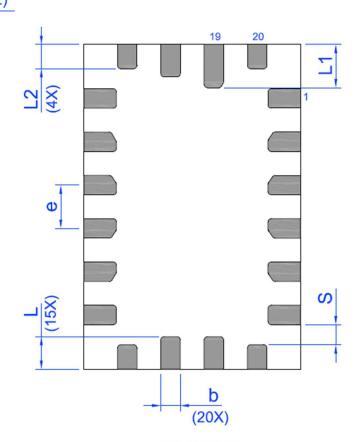
The IC security bit is locked/set for code security for production unless otherwise specified. The Programming Code Number is not changed based on the choice of locked vs. unlocked status.



## **Package Drawing and Dimensions**

## STQFN 20L 2x3mm 0.4P FCD Package JEDEC MO-220, Variation WECE





## **Marking View**



**BTM View** 

## Unit: mm

Symbol	Min	Nom.	Max	Symbol	Min	Nom.	Max
Α	0.50	0.55	0.60	D	2.95	3.00	3.05
A1	0.005	-	0.050	Е	1.95	2.00	2.05
A2	0.10	0.15	0.20	L	0.25	0.30	0.35
b	0.13	0.18	0.23	L1	0.35	0.40	0.45
е	(	0.40 BSC		L2	0.175	0.225	0.275
S	C	.185 TYP					

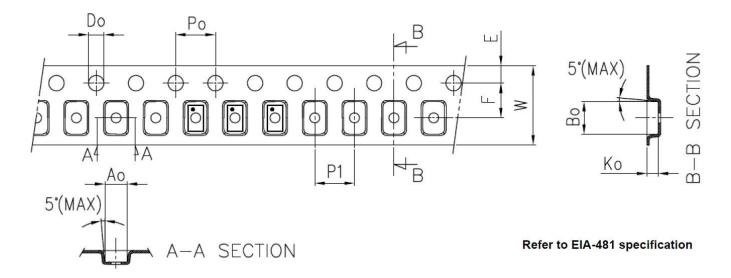


## **Tape and Reel Specification**

Package Type	# of Pins	Nominal Package Size [mm]	Max Units			Leader (min)		Trailer (min)		Таре	Part
			per Reel	per Box	Reel & Hub Size [mm]	Pockets	Length [mm]	Pockets	Length [mm]	Width [mm]	Pitch [mm]
STQFN 20L 2x3mm 0.4P FCD	20	2 x 3 x 0.55	3000	3000	178/60	100	400	100	400	8	4

### **Carrier Tape Drawing and Dimensions**

Package Type	Pocket BTM Length	Pocket BTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge	Index Hole to Pocket Center	Tape Width
	A0	В0	K0	P0	P1	D0	E	F	W
STQFN 20L 2x3mm 0.4P FCD	2.2	3.15	0.76	4	4	1.5	1.75	3.5	8



## **Recommended Reflow Soldering Profile**

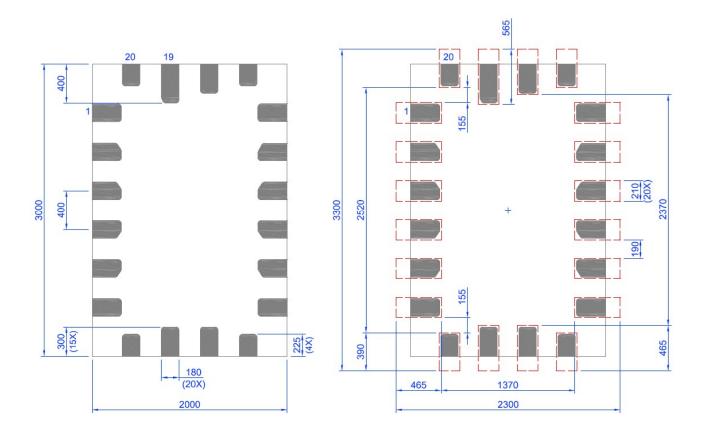
Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 3.30 mm³ (nominal). More information can be found at <a href="https://www.jedec.org">www.jedec.org</a>.



### **Recommended Land Pattern**

Exposed Pad (PKG face down)

Recommended Land Pattern (PKG face down)



Unit:um



**Datasheet Revision History** 

Date	Version	Change
07/13/2023	0.10	New design

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